Analog Power AM2329P

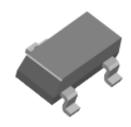
P-Channel 30V (D-S) MOSFET

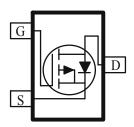
These miniature surface mount MOSFETs utilize High Cell Density process. Low r_{DS(on)} assures minimal power loss and conserves energy, making this device ideal for use in power management circuitry. Typical applications are power switch, power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

•	Low r _{DS(on)} Provides Higher Efficiency and
	Extends Battery Life

- Low Gate Charge
- Fast Switch
- Miniature SOT-23 Surface Mount Package Saves Board Space

PRODUCT SUMMARY			
V _{DS} (V)	$r_{DS(on)}(\Omega)$ $I_D(A)$		
-30	$0.112 @ V_{GS} = 10 V$	2.5	
-30	$0.172 @ V_{GS} = 4.5V$	2.0	





ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C UNLESS OTHERWISE NOTED)				
Parameter		Symbol	Maximum	Units
Drain-Source Voltage		V_{DS}	-30	V
Gate-Source Voltage		V_{GS}	±20	V
Continuous Dunin Comment ^a	$T_A=25^{\circ}C$	T.,	2.5	
Continuous Drain Current ^a	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	П	1.7	A
Pulsed Drain Current ^b		I_{DM}	±12	
Continuous Source Current (Diode Conduction) ^a		I_S	1.25	Α
D D a	$T_A=25^{\circ}C$	$\Big]_{\mathbf{D}_{-}}$	1.3	W
Power Dissipation ^a	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	Гр	0.8	
Operating Junction and Storage Temperature Range		T_{J}, T_{stg}	-55 to 150	°C

THERMAL RESISTANCE RATINGS					
Parameter	Symbol	Maximum	Units		
N. T. (* A. 1 · (a	t <= 5 sec	D	100	0C/M	
Maximum Junction-to-Ambient ^a	Steady-State	R_{THJA}	166	C/W	

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Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

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Danamakan	G1 1	T. A.C. PA	Limits			TT •4
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Static						
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = 250 \text{ uA}$	1.0			V
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0 \ V, \ V_{GS} = \pm 20 \ V$			±100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = -24 \text{ V}, V_{GS} = 0 \text{ V}$			1	uA
-	1088	$V_{DS} = -24 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			50	
On-State Drain Current ^A	$I_{D(on)}$	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	10			Α
Drain-Source On-Resistance ^A	r _{ng()}	$V_{GS} = 10 \text{ V}, I_D = 2.5 \text{ A}$			112	mΩ
Diani-Source On-Resistance	$r_{\mathrm{DS(on)}}$	$V_{GS} = 4.5 \text{ V}, I_D = 2.0 \text{ A}$			172	
Forward Tranconductance ^A	$g_{ m fs}$	$V_{DS} = 4.5 \text{ V}, I_{D} = 2.5 \text{ A}$		5		S
Diode Forward Voltage	V_{SD}	$I_S = 0.75 \text{ A}, V_{GS} = 0 \text{ V}$			1.2	V
Dynamic ^b						
Total Gate Charge	Q_{g}			4.5		
Gate-Source Charge	Q_{gs}	$V_{DS} = 30 \text{ V}, V_{GS} = 5 \text{ V}, I_D = 2.5 \text{ A}$		1.4		nC
Gate-Drain Charge	Q_{gd}			2.4		
Turn-On Delay Time	t _{d(on)}			9		
Rise Time	$t_{\rm r}$	$V_{DD} = 30 \text{ V}, R_L = 30 \Omega, I_D = 1 \text{ A},$		12		na.
Turn-Off Delay Time	t _{d(off)}	$V_{GEN} = 10 \text{ V}$		25		ns
Fall-Time	t_{f}			14		

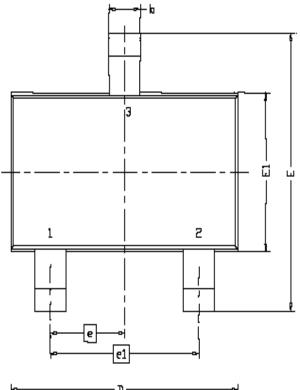
Notes

- a. Pulse test: $PW \le 300us duty cycle \le 2\%$.
- b. Guaranteed by design, not subject to production testing.

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Package Information

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DIM.	MILLIMETERS			
ייונת	MIN	NDM	MAX	
Α	0.935	0.95	1.10	
A1	0.01	-	0.10	
A2	0.85	0.90	1.925	
Ь	0.30	0.40	0.50	
С	0.10	0.15	0,25	
D	2.70	2.90	3.10	
П	2.60	2.80	3.00	
E1	1.40	1.60	1.80	
6	0.95 BSC			
el	1.90 BSC			
Г	0.30	0.40	0.60	
L1	0.60REF			
LZ	0,25BSC			
R	0.10			
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01	7*N□M			

